CY54FCT543T . . . D PACKAGE

CY7

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- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- 3-State Outputs
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Separation Controls for Data Flow in Each Direction
- Back-to-Back Latches for Storage
- CY54FCT543T
 - 48-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT543T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

description

The 'FCT543T octal latched transceivers contain two sets of eight D-type latches with separate latch-enable (LEAB, LEBA) and output-enable (OEAB, OEBA) inputs for each set to permit independent control of input and output in either direction of data flow. For data flow from A to B, for example, the A-to-B enable (CEAB) input must be low in order to enter data from A or to take data from B, as indicated in the function table. With CEAB low, a low signal on the A-to-B latch-enable (LEAB) input makes the A-to-B latches transparent; a subsequent low-to-high transition of the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB low, the 3-state B-output buffers are active and reflect the data present at the output of the A latches. Control of data from B to A is similar, but uses CEBA, LEBA, and OEBA inputs.

These devices are fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 2001, Texas Instruments Incorporated On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

	Q (TOP VI		SO PACKAGE
LEBA OEBA A ₀ A ₁ A ₂ A ₂ A ₃ A ₄ A ₅ CEAB GND	5 6 7	24 23 22 21 20 19 18 17 16 15 14 13	V _{CC} CEBA B ₀ B ₂ B ₃ B ₄ B ₅ B ₆ B ₇ LEAB OEAB

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PIN DESCRIPTION

NAME	DESCRIPTION
OEAB	A-to-B output-enable input (active low)
OEBA	B-to-A output-enable input (active low)
CEAB	A-to-B enable input (active low)
CEBA	B-to-A enable input (active low)
LEAB	A-to-B latch-enable input (active low)
LEBA	B-to-A latch-enable input (active low)
А	A-to-B data inputs or B-to-A 3-state outputs
В	B-to-A data inputs or A-to-B 3-state outputs

ORDERING INFORMATION

TA	PAC	KAGE [†]	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	5.3	CY74FCT543CTQCT	FCT543C
	SOIC - SO	Tube	5.3	CY74FCT543CTSOC	FCT543C
	5010 - 50	Tape and reel	5.3	CY74FCT543CTSOCT	FC1543C
	QSOP – Q	Tape and reel	6.5	CY74FCT543ATQCT	FCT543A
–40°C to 85°C	SOIC - SO	Tube	6.5	CY74FCT543ATSOC	FCT543A
	3010 - 30	Tape and reel	6.5	CY74FCT543ATSOCT	FC1545A
	QSOP – Q	Tape and reel	8.5	CY74FCT543TQCT	FCT543
	SOIC - SO	Tube	8.5	CY74FCT543TSOC	FCT543
	3010 - 30	Tape and reel	8.5	CY74FCT543TSOCT	FC1545
–55°C to 125°C	CDIP – D	Tube	10	CY54FCT543TDMB	
-55°C 10 125°C		Tube	10	CY54FCT543TLMB	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

	INPUTS		LATCH	OUTPUT
CEAB	LEAB	OEAB	A TO B§	В
Н	Х	Х	Storing	Z
Х	Н	Х	Storing	Х
Х	Х	Н	х	Z
L	L	L	Transparent	Current A inputs
L	Н	L	Storing	Previous A inputs

FUNCTION TABLE[‡]

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

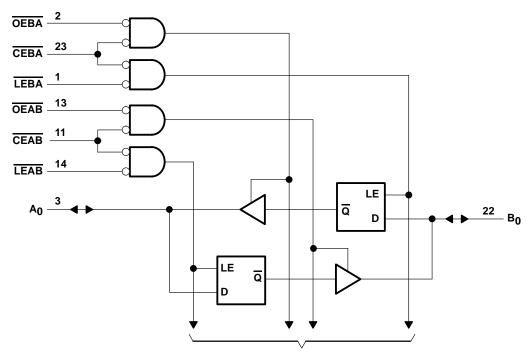
 $\frac{1}{4}$ A-to-B data flow shown; B-to-A flow control is the same, except uses CEBA, LEBA, and OEBA.

§ Before LEAB low-to-high transition



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logic diagram (positive logic)



To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package	61°C/W
SO package	46°C/W
Ambient temperature range with power applied, T _A	. –65°C to 135°C
Storage temperature range, T _{stg}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

		CY	54FCT54	3T	CY	74FCT54	3T	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
VCC	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
\vee_{IL}	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			-12			-32	mA
IOL	Low-level output current			48			64	mA
ТĄ	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

		TEAT CONDITION	10	CY	54FCT54	I3T	CY	74FCT54	I3T	
PARAMETER		TEST CONDITIO	NS	MIN	түр†	MAX	MIN	TYP [†]	MAX	UNIT
Mu e	V _{CC} = 4.5 V,	I _{IN} = -18 mA			-0.7	-1.2				v
VIK	V _{CC} = 4.75 V,	I _{IN} = -18 mA						-0.7	-1.2	v
	V _{CC} = 4.5 V,	I _{OH} = -12 mA		2.4	3.3					
VOH	V _{CC} = 4.75 V	I _{OH} = -32 mA					2			V
	VCC = 4.75 V	I _{OH} = -15 mA					2.4	3.3		
Ve	V _{CC} = 4.5 V,	I _{OL} = 48 mA			0.3	0.55				v
VOL	V _{CC} = 4.75 V,	I _{OL} = 64 mA						0.3	0.55	v
V _{hys}	All inputs				0.2			0.2		V
1.	V _{CC} = 5.5 V,	$V_{IN} = V_{CC}$				5				
lj –	V _{CC} = 5.25 V,	$V_{IN} = V_{CC}$							5	μA
	V _{CC} = 5.5 V,	V _{IN} = 2.7 V				±1				μA
ін	V _{CC} = 5.25 V,	V _{IN} = 2.7 V							±1	μ
i	V _{CC} = 5.5 V,	V _{IN} = 0.5 V				±1				
١Ľ	V _{CC} = 5.25 V,	V _{IN} = 0.5 V							±1	μA
loru	V _{CC} = 5.5 V,	V _{OUT} = 2.7 V				10				μA
IOZH	V _{CC} = 5.25 V,	V _{OUT} = 2.7 V							10	μ
1071	$V_{CC} = 5.5 V,$	V _{OUT} = 0.5 V				-10				μA
IOZL	$V_{CC} = 5.25 V,$	V _{OUT} = 0.5 V							-10	μ
last	V _{CC} = 5.5 V,	V _{OUT} = 0 V		-60	-120	-225				m/
los‡	V _{CC} = 5.25 V,	V _{OUT} = 0 V					-60	-120	-225	
l _{off}	$V_{CC} = 0 V,$	V _{OUT} = 4.5 V				±1			±1	μA
laa	V _{CC} = 5.5 V,	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 V$		0.1	0.2				m/
ICC	V _{CC} = 5.25 V,	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 V$					0.1	0.2	117
∆ICC	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN}$	= 3.4 V§, f ₁ = 0, Ou	itputs open		0.5	2				m/
	V _{CC} = 5.25 V, V _{IN}	1 = 3.4 V§, f ₁ = 0, O	utputs open					0.5	2	1117
1000		ig at 5 <u>0% dut</u> y cycle = low, CEBA = high			0.06	0.12				mA
ICCD		ig at 50% duty cycle = low, CEBA = high					0.06	0.12	MH	

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

* Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

§ Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

 \P This parameter is derived for use in total power-supply calculations.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETED	-		с.	CY	54FCT54	I3T	CY	74FCT54	3T	
PARAMETER		EST CONDITION	5	MIN	түр†	MAX	MIN	түр†	MAX	UNIT
	V _{CC} = 5.5 V,	One bit switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ \text{or} \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$		0.7	1.4				
	f ₀ = 10 MHz, Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4				
	$\overline{CEAB} \text{ and } \overline{OEAB} = $ $low, \overline{CEBA} = high,$ $f_0 = \overline{LEAB} = 10 \text{ MHz}$	Eight bits switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ \text{or} \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$		2.8	5.6ll				
IC#		at 50% duty cycle	$V_{IN} = 3.4 V \text{ or GND}$		5.1	14.6				mA
IC.	V _{CC} = 5.25 V,	One bit switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ \text{or} \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$					0.7	1.4	IIIA
	f ₀ = 10 MHz, Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 V \text{ or GND}$					1.2	3.4	
	$\overline{CEAB} \text{ and } \overline{OEAB} = \\ \text{low, } \overline{CEBA} = \text{high,} \\ f_0 = \overline{LEAB} = 10 \text{ MHz}$	Eight bits switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ \text{or} \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$					2.8	5.6ll	
		at 50% duty cycle	$V_{IN} = 3.4 V \text{ or GND}$					5.1	14.6ll	
Ci					5	10		5	10	pF
Co					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 ΔI_{CC} = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

 D_H = Duty cycle for TTL inputs high

 N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero fo

= Input signal frequency f1

= Number of inputs changing at f1 N₁

All currents are in milliamperes and all frequencies are in megahertz.

Il Values for these conditions are examples of the I_{CC} formula.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	PARAMETER	CY54FC	CY54FCT543T		CY74FCT543T		543AT	CY74FCT	543CT	UNIT
FARAIVIETER		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
tw	Pulse duration, LEAB or LEBA	5		5		5		5		ns
t _{su}	Setup time, data before $\overline{LEAB}\downarrow$ or $\overline{LEBA}\downarrow$	3		2		2		2		ns
t _h	Hold time, data after $\overline{LEAB}\downarrow$ or $\overline{LEBA}\downarrow$	2		2		2		2		ns



CY54FCT543T, CY74FCT543T 8-BIT LATCHED REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS SCCS030A - MAY 1994 - REVISED OCTOBER 2001

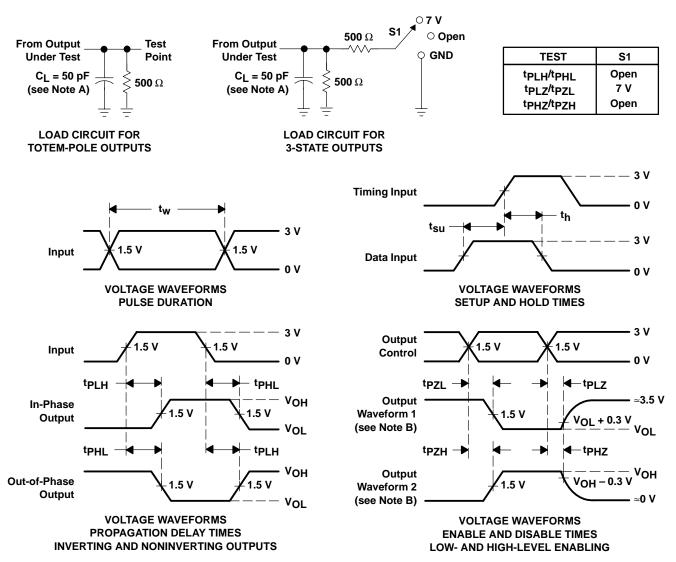
switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY54FC	T543T	CY74FC	T543T	CY74FC1	543AT	CY74FCT	543CT	UNIT
FARAIVIETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	A or B	B or A	2	10	2.5	8.5	2.5	6.5	2.5	5.3	ns
^t PHL	AUB	BUR	2	10	2.5	8.5	2.5	6.5	2.5	5.3	115
^t PLH	LEBA or LEAB	A or B	2.5	14	2.5	12.5	2.5	8	2.5	7	ns
^t PHL	LEBA OI LEAD	AUB	2.5	14	2.5	12.5	2.5	8	2.5	7	115
^t PZH		A or B	2	14	2	12	2	9	2	8	ns
^t PZL		AUB	2	14	2	12	2	9	2	8	115
^t PZH		A or B	2	14	2	12	2	9	2	8	ns
^t PZL		AUB	2	14	2	12	2	9	2	8	115
^t PHZ		A or P	2	13	2	9	2	7.5	2	6.5	-
^t PLZ	OEBA or OEAB	BA or OEAB A or B	2	13	2	9	2	7.5	2	6.5	ns
^t PHZ	CEBA or CEAB A or B		2	13	2	9	2	7.5	2	6.5	
^t PLZ		AUID	2	13	2	9	2	7.5	2	6.5	ns



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NOTES: A. CL includes probe and jig capacitance.

 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





25-Oct-2016

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9222101M3A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9222101M3A CY54FCT 543TLMB	Samples
5962-9222101MLA	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9222101ML A CY54FCT543TDMB	Samples
CY54FCT543TDMB	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9222101ML A CY54FCT543TDMB	Samples
CY54FCT543TLMB	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9222101M3A CY54FCT 543TLMB	Samples
CY74FCT543ATQCT	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT543A	Samples
CY74FCT543ATSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT543A	Samples
CY74FCT543ATSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT543A	Samples
CY74FCT543TQCT	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT543	Samples
CY74FCT543TSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT543	Samples
CY74FCT543TSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT543	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



25-Oct-2016

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

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⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



ř	*All dimensions are nominal Device Package Package Pins SPQ Reel A0 B0 K0 P1 W												D : 4
	Device	Раскаде Туре	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	CY74FCT543ATQCT	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
	CY74FCT543TQCT	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
	CY74FCT543TSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

2-Sep-2015



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT543ATQCT	SSOP	DBQ	24	2500	367.0	367.0	38.0
CY74FCT543TQCT	SSOP	DBQ	24	2500	367.0	367.0	38.0
CY74FCT543TSOCT	SOIC	DW	24	2000	367.0	367.0	45.0

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